BORN SEMICONDUCTOR

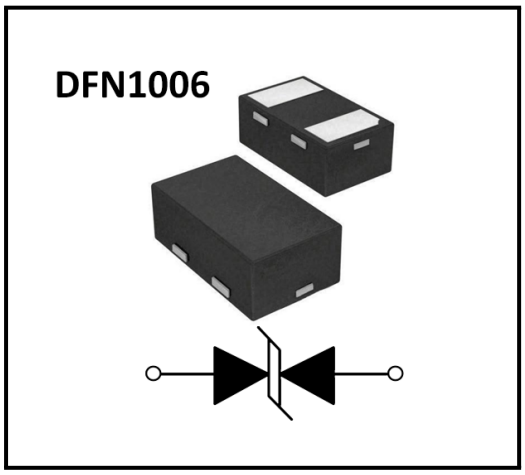
# BNAZ9808-01F

**ESD Protection Diode**

## Features

- 440Watts peak pulse power (tp = 8/20μs)
- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping Voltage
- Low leakage current
- Protection one data/power line
- IEC 61000-4-2 ±30kV contact ; ±30kV air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 20A (8/20μs)

## Package



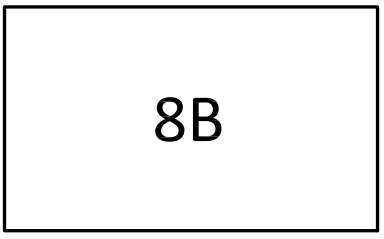

## Applications

- Microprocessor based equipments
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation
- Pagers Peripherals

## Mechanical Characteristics

- DFN1006 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

## Marking




## Ordering information

| Order code | Package | Base qty | Delivery mode |
|---|---|---|---|
| BNAZ9808-01F | DFN1006 | 10k | Tape and reel |

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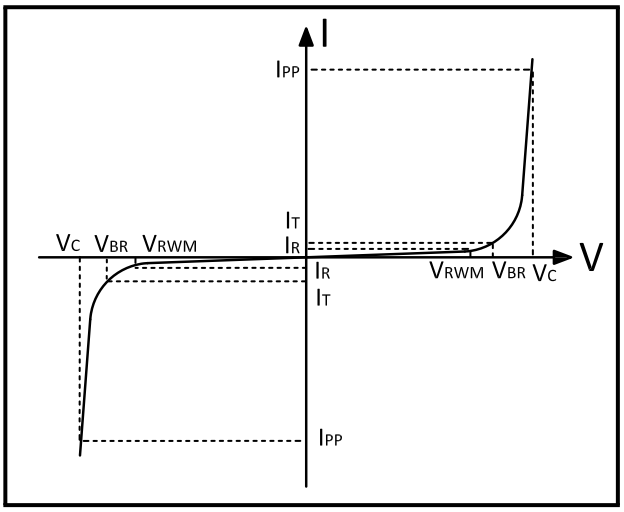
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# BNAZ9808-01F

**ESD Protection Diode**

## Electrical Parameters ($T_A$ = 25°C unless otherwise noted)

| Symbol | Parameter |
|---|---|
| $I_{PP}$ | Maximum Reverse Peak Pulse Current |
| $V_C$ | Clamping Voltage @ $I_{PP}$ |
| $V_{RWM}$ | Peak Reverse Working Voltage |
| $I_R$ | Reverse Leakage Current @ $V_{RWM}$ |
| $V_{BR}$ | Breakdown Voltage @ $I_T$ |
| $I_T$ | Test Current |
| | |
| | |
| | |




Note:8/20us pulse Waveform.

## Absolute Maximum Rating

| Rating | Symber | Value | Units |
|---|---|---|---|
| Peak Pulse Power ( tp =8/20μs ) | $P_{PP}$ | 440 | Watts |
| Peak Pulse Current (tp =8/20μs ) | $I_{PP}$ | 20 | A |
| ESD per IEC 61000-4-2 (Air)<br>ESD per IEC 61000-4-2 (Contact) | $V_{ESD}$ | 30<br>30 | KV |
| Lead Soldering Temperature | $T_L$ | 260(10seconds) | °C |
| Junction Temperature | $T_J$ | -55 to + 150 | °C |
| Storage Temperature | $T_{stg}$ | -55 to + 150 | °C |

## Electrical Characteristics

| Parameter | Symber | Conditions | Min | Typical | Max | Units |
|---|---|---|---|---|---|---|
| Reverse Stand-Off Voltage | $V_{RWM}$ | – | – | – | 8.0 | V |
| Reverse Breakdown Voltage | $V_{BR}$ | $I_T$=1mA | 9.0 | – | – | V |
| Reverse Leakage Current | $I_R$ | $V_{RWM}$=8V,T=25°C | – | 0.1 | 0.5 | uA |
| Peak Pulse Current | $I_{PP}$ | tp =8/20μs | – | – | 20 | A |
| Clamping Voltage | $V_C$ | $I_{PP}$=20A, tp =8/20us | – | 19 | 22 | V |
| Junction Capacitance | $C_j$ | $V_R$=0V,f=1MHZ | – | 63 | 70 | pF |

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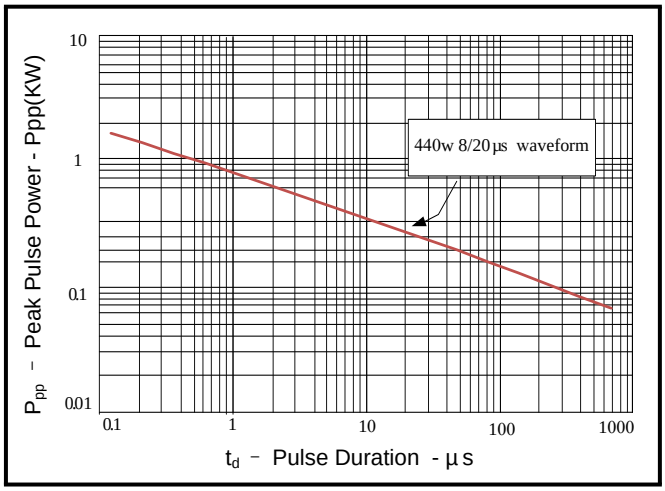
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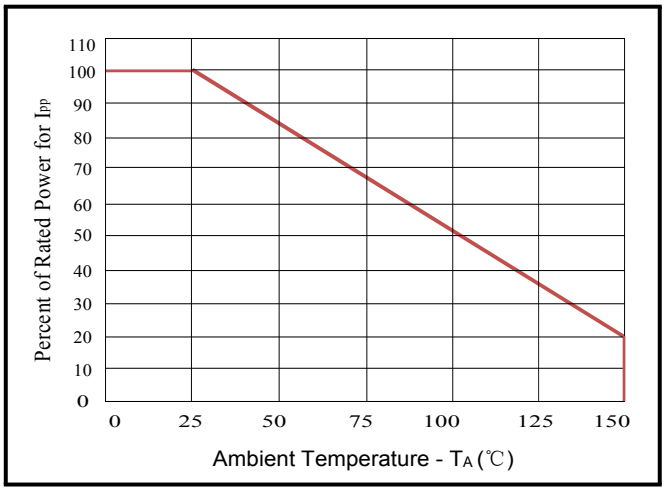
**ESD Protection Diode**

## Typical Characteristics

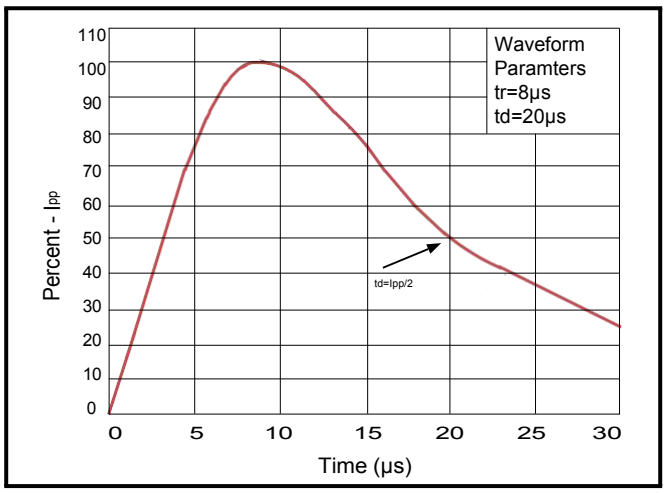
### Figure 1: Peak Pulse Power vs. Pulse Time



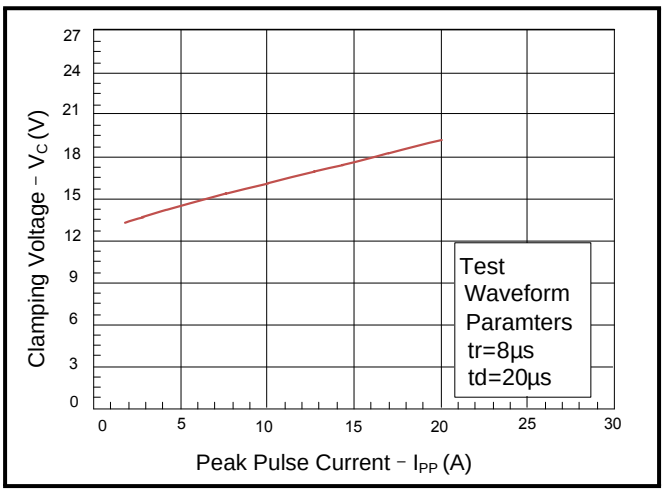

### Figure 2: Power Derating Curve




### Figure 3: Pulse Waveform




### Figure 4: Clamping Voltage vs. $I_{PP}$



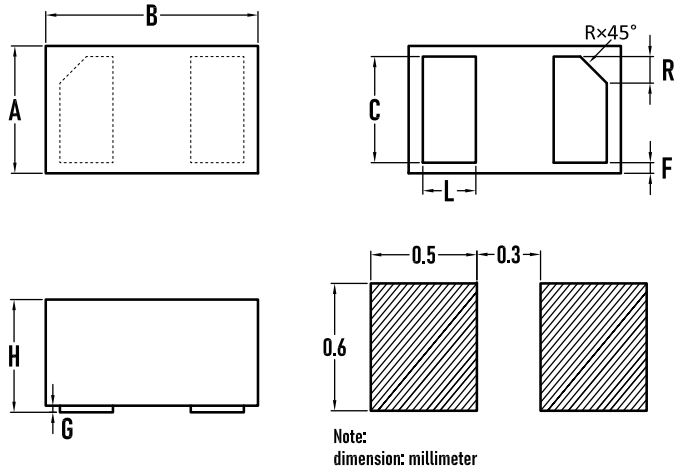

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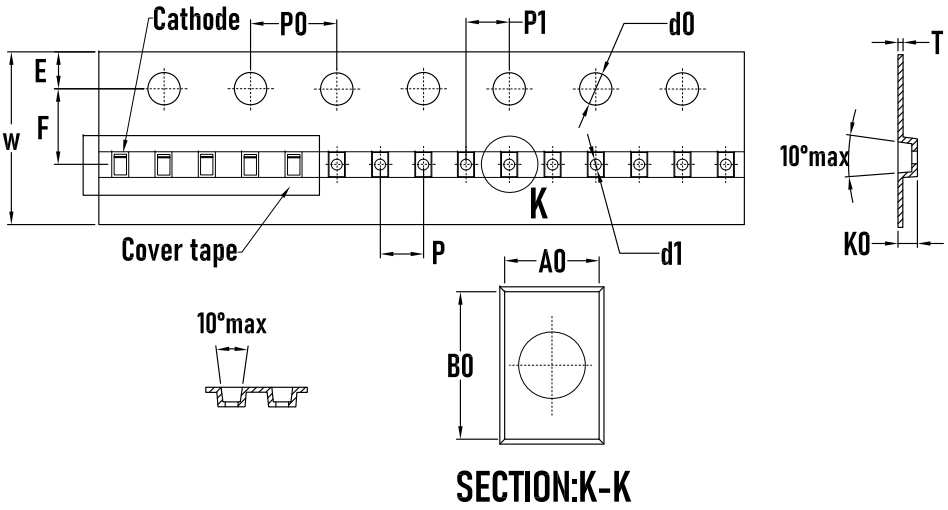
**ESD Protection Diode**

## Outline Drawing – DFN1006



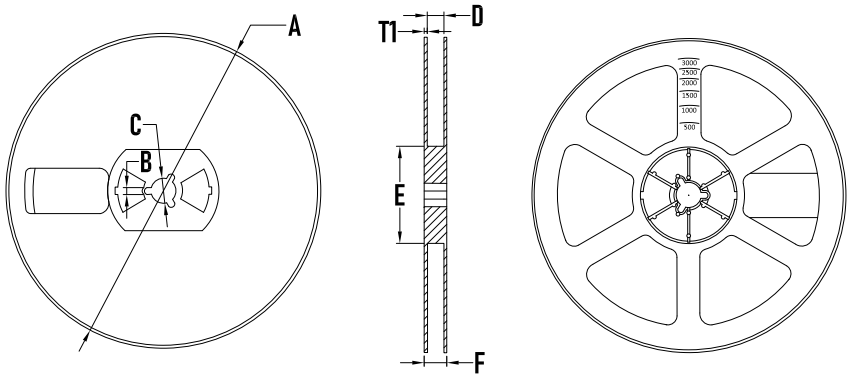

| SYMBOL | MILLIMETER | | |
|---|---|---|---|
| | MIN. | Typ. | MAX. |
| A | 0.55 | 0.60 | 0.65 |
| B | 0.95 | 1.00 | 1.05 |
| C | 0.45 | 0.50 | 0.55 |
| L | 0.20 | 0.25 | 0.30 |
| F | | 0.05REF | |
| G | 0.00 | 0.02 | 0.05 |
| H | 0.45 | 0.50 | 0.55 |
| R | 0.07 | 0.12 | 0.17 |

## Packaging Tape - DFN1006




| SYMBOL | MILLIMETER |
|---|---|
| A0 | 0.71±0.05 |
| B0 | 1.11±0.05 |
| d0 | $1.5^{+0.1}_{-0}$ |
| d1 | 0.50±0.05 |
| E | 1.75±0.10 |
| F | 3.50±0.05 |
| K0 | 0.56±0.05 |
| P | 2.00±0.05 |
| P0 | 4.00±0.10 |
| P1 | 2.00±0.05 |
| W | $8.00^{+0.03}_{-0.01}$ |
| T | 0.2±0.015 |

## Packaging Reel




| SYMBOL | MILLIMETER |
|---|---|
| A | 178±1 |
| B | 3.5±0.2 |
| C | 14.3±0.2 |
| D | $9.8^{+2}_{-1}$ |
| E | 54.5±0.5 |
| F | 12.4±0.2 |
| T1 | 1.0±0.2 |
| Quantity | 10000PCS |

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